

# 16A, 35V - 150V Schottky Barrier Surface Mount Rectifier

## FEATURES

- AEC-Q101 qualified
- Low power loss, high efficiency
- Ideal for automated placement
- Guard ring for overvoltage protection
- High surge current capability
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

# APPLICATIONS

- Low voltage, high freq. inverter
- DC/DC converter
- Freewheeling diodes
- Reverse battery protection
- Car lighting

# **MECHANICAL DATA**

- Case: TO-263AB (D<sup>2</sup>PAK)
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 1.37g (approximately)

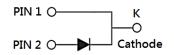
KEY PARAMETERS			
PARAMETER	VALUE	UNIT	
I <sub>F</sub>	16	А	
V <sub>RRM</sub>	35 - 150	V	
I <sub>FSM</sub>	150	А	
T <sub>J MAX</sub>	150	°C	
Package	TO-263AB (D <sup>2</sup> PAK)		
Configuration	Single	die	



HALOGEN



TO-263AB (D<sup>2</sup>PAK)



		MBRS	MBRS	MBRS	MBRS	MBRS	MBRS	MBRS	
PARAMETER	SYMBOL	1635	1645	1650	1660	1690	16100	16150	UNIT
		н	н	н	н	н	н	н	
Marking code on the device		MBRS 1635	MBRS 1645	MBRS 1650	MBRS 1660	MBRS 1690	MBRS 16100	MBRS 16150	
Repetitive peak reverse voltage	$V_{RRM}$	35	45	50	60	90	100	150	V
Reverse voltage, total rms value	V <sub>R(RMS)</sub>	24	31	35	42	63	70	105	V
Forward current	I <sub>F</sub>				16				Α
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I <sub>FSM</sub>	ѕм 150			A				
Peak repetitive reverse surge current <sup>(1)</sup>	I <sub>RRM</sub>	RRM 1 0.5			А				
Peak repetitive forward current (Rated V <sub>R</sub> , Square wave, 20KHz)	I <sub>FRM</sub>	I <sub>FRM</sub> 32			Α				
Junction temperature	T <sub>J</sub> -55 to +150			°C					
Storage temperature	T <sub>STG</sub> -55 to +175		°C						

#### Notes:

1. tp = 2.0µs, 1.0KHz



THERMAL PERFORMANCE			
PARAMETER	SYMBOL	ТҮР	UNIT
Junction-to-case thermal resistance	R <sub>eJC</sub>	1.5	°C/W

ELECTRICAL SPECIFICATIONS (T <sub>A</sub> = 25°C unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
	MBRS1635H MBRS1645H	I <sub>F</sub> = 16A, T <sub>J</sub> = 25°C	V <sub>F</sub>	-	0.63	V
	MBRS1650H MBRS1660H			-	0.75	V
	MBRS1690H MBRS16100H			-	0.85	V
Forward voltage <sup>(1)</sup>	MBRS16150H			-	0.95	V
Forward voltage	MBRS1635H MBRS1645H	. I <sub>F</sub> = 16A, T <sub>J</sub> = 125°C		-	0.57	V
	MBRS1650H MBRS1660H			-	0.65	V
	MBRS1690H MBRS16100H			-	0.82	V
	MBRS16150H			-	0.92	V
Reverse current @ rated V <sub>R</sub> <sup>(2)</sup>	MBRS1635H MBRS1645H MBRS1650H MBRS1660H	T <sub>J</sub> = 25°C	I <sub>R</sub>	-	500	μΑ
	MBRS1690H MBRS16100H			-	300	μΑ
	MBRS16150H			-	100	μΑ
	MBRS1635H MBRS1645H	T <sub>J</sub> = 125°C		-	15	mA
	MBRS1650H MBRS1660H			-	10	mA
	MBRS1690H MBRS16100H			-	7.5	mA
	MBRS16150H			-	5	mA

## Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

ORDERING INFORMATION		
ORDERING CODE <sup>(1)</sup>	PACKAGE	PACKING
MBRS16xH	TO-263AB (D <sup>2</sup> PAK)	800 / Tape & Reel

Notes:

1. "x" defines voltage from 35V(MBRS1635H) to 150V(MBRS16150H)



## **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

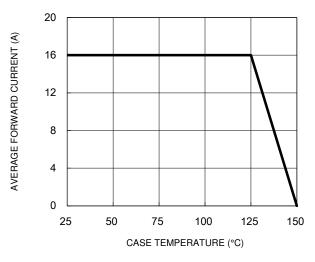
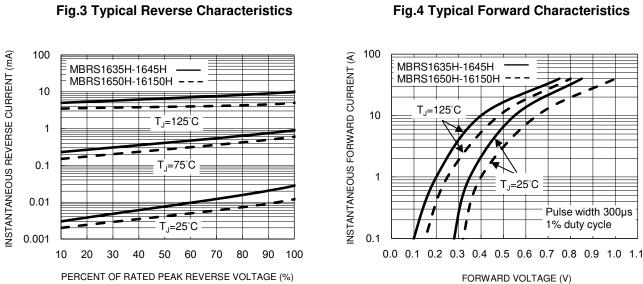


Fig.1 Forward Current Derating Curve



10000

1000

100 L

CAPACITANCE (pF)

#### Fig.5 Maximum Non-Repetitive Forward Surge Current

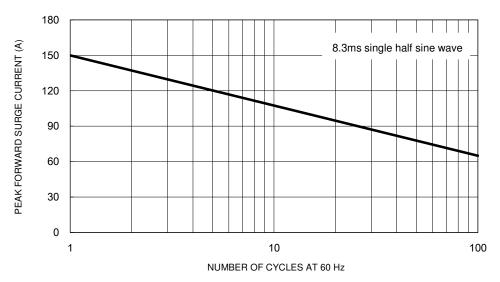


Fig.2 Typical Junction Capacitance

MBRS1650H -MBRS16150H

1

f=1.0MHz Vsig=50mVp-p

MBRS1635H - MBRS1645H

10

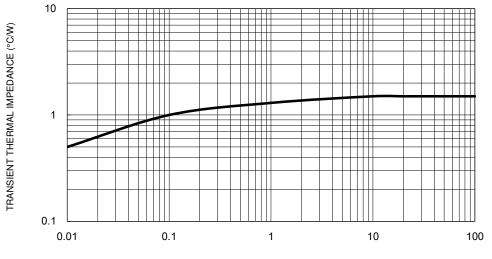
REVERSE VOLTAGE (V)

100



# **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 



### Fig.6 Typical Transient Thermal Impedance

PULSE DURATION (s)

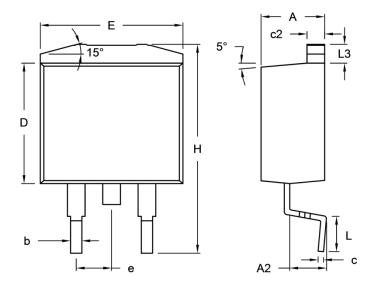


# MBRS1635H - MBRS16150H

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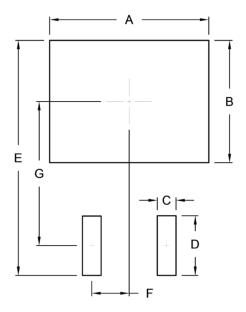
# **PACKAGE OUTLINE DIMENSIONS**

# TO-263AB (D<sup>2</sup>PAK)



DIM.	Unit (mm)		Unit (	(inch)	
	Min.	Max.	Min.	Max.	
A	4.44	4.70	0.175	0.185	
A2	2.03	2.79	0.080	0.110	
b	0.68	0.94	0.027	0.037	
с	0.36	0.53	0.014	0.021	
c2	1.14	1.40	0.045	0.055	
D	8.25	9.25	0.325	0.364	
E	-	10.50	-	0.413	
е	2.41	2.67	0.095	0.105	
н	14.60	15.88	0.575	0.625	
L	2.29	2.79	0.090	0.110	
L3	1.14	1.40	0.045	0.055	

# SUGGESTED PAD LAYOUT



#### Unit (mm) Unit (inch) Symbol Α 10.80 0.425 В 0.327 8.30 С 1.27 0.050 D 4.05 0.159 Е 15.95 0.628 F 2.54 0.100 G 9.775 0.385

## **MARKING DIAGRAM**



P/N	= Marking Code
G	= Green Compound
YWW	= Date Code
F	= Factory Code



# MBRS1635H - MBRS16150H

Taiwan Semiconductor

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